	70		_= -	:
L Number	Hits	Search Text (soi or (semiconductor adj on ad)	DB USPAT;	Time stamp
120	7515	insulat\$3)) near2 substrate	US-PGPUB;	2003/11/0/ 10:25
!		Indicated 3// Heart Substitute	EPO; JPO;	
i			DERWENT;	!
i	1		IBM_TDB	1
27	100	(silicon near2 carbide) near2 boat	USPAT;	2003/11/07 18:30
i			US-PGPUB;	1
1	!		EPO; JPO;	į l
1	1		DERWENT; IBM TDB	
28	2	((soi or(semiconductor adj on adj	USPAT;	2003/11/07 18:30
120	1	insulat\$3)) near2 substrate) same	US-PGPUB;	12003/12/0/ 10:30
i	i	((silicon near2 carbide) near2 boat)	EPO; JPO;	1 1
1			DERWENT;	1 1
:	!	i	IBM_TDB	1
1-	34	silicon adj boat	USPAT;	2002/11/20 18:41
1	1		US-PGPUB;	I .
1	1		EPO; JPO;	
1	i		DERWENT;	1 1
1 -	34	silicon adj boat	USPAT;	2002/11/20 11:08
ì	1	STITCON day boat	US-PGPUB;	i 2002/11/20 11.00
i	1	l	EPO; JPO;	
	i	I	DERWENT;	1
		L .	IBM_TDB	I
! -	60174	silicon adj carbide	USPAT;	2002/11/20 18:18
1	1		US-PGPUB;	
1	1		EPO; JPO; DERWENT;	
1	1		IBM TDB	(
1_	92082		USPAT;	2002/11/20 18:18
1	1	1	US-PGPUB;	(
1	I		EPO; JPO;	
j	I	I	DERWENT;	
1		1	IBM_TDB	
1	2120	(silicon adj carbide) same cvd		2002/11/20 18:18
i .			US-PGPUB; EPO; JPO;	١
1	-		DERWENT;	
1	!		IBM TDB	1
1_	66246	boat	USPAT;	2002/11/20 18:18
1			US-PGPUB;	
ì	1	1	EPO; JPO;	1
1	1	1	DERWENT;	'
i_	. 41	((silicon adj carbide) same cvd) same boat	IBM_TDB USPAT;	2002/11/20 18:18
1.	1 41	. ((SIIICON AU) CAIDIUG/ SAME CVU/ SAME DOAL	US-PGPUB;	1 2004/11/20 10:10
T	1	1	EPO; JPO;	
1	1	1	DERWENT:	1
1	1		IBM_TDB	
1 -	34	silicon adj boat	USPAT;	2002/11/21 19:44
1	1	1	US-PGPUB;	
		<u> </u>	EPO; JPO; DERWENT;	1
1			IBM TDB	
! -	1	(((silicon adj carbide) same cvd) same	USPĀT;	2002/11/20 18:43
1			US-PGPUB;	,
1	l .		EPO; JPO;	
1	(DERWENT;	
1		1	IBM_TDB	
1 -		(((silicon adj carbide) same cvd) same		2002/11/20 18:43
1	i	boat) or (silicon adj boat)	US-PGPUB; EPO; JPO;	1
1	ı		DERWENT;	l .
1	I		IBM TDB	
1 -	14400	soi	USPAT;	2002/11/21 19:43
1	i	I	US-PGPUB;	į
1	ı	1	EPO; JPO;	i
!	1		DERWENT; IBM TDB	
l	L		IDM TUB	

<u> </u>	34	silicon adj boat	USPAT; US-PGPUB;	2002/11/21 19	:44
	!		EPO; JPO; DERWENT;	i İ	- 1
1_	1	soi same (silicon adj boat)	IBM_TDB USPAT;	 2002/11/21 19	اعدا
į -		Sol Same (Silicon ad) boat)	US-PGPUB;	2002/11/21 19	.40
i	1		EPO; JPO;	1	,
}	i		DERWENT;	l .	- 1
1 _	1146922		IBM_TDB USPAT;	 2002/11/21 19	:50
	1		US-PGPUB;		1
!	!	1	EPO; JPO;	l I	l l
i	i	İ	DERWENT;	l .	1
¦ -	. 5	(silicon adj boat) same semiconductor	USPAT;	2002/11/21 19	:46
1	1	1	US-PGPUB;	1	1
l L	i	h I	EPO; JPO; DERWENT;	i	
i	1	<u> </u>	IBM TDB	l .	i
; -	. 12	semiconductor adj on adj insulat\$3	USPAT;	2003/11/07 18	:28
i	1	1	US-PGPUB; EPO; JPO;	!	i
l :	1		DERWENT;	1	1
		1	IBM_TDB		
	14562		USPAT; US-PGPUB;	2002/12/02 11	:04
i	1		EPO; JPO;	ī	- 1
1	i		DERWENT;	1	- 1
! _	508529		IBM TDB	, 2002/12/02 11	.04
	1 200323	I CLANDED CO.	US-PGPUB;	2002/12/02 11	.04
!	i	1	EPO; JPO;	1	1
i	i		DERWENT; IBM TDB	1	i
-	3801	soi same transistor	USPĀT;	2002/12/02 11	:04
	i		US-PGPUB;	1	i
	1		EPO; JPO; DERWENT;	1	1
1	l	I	IBM TDB	1	1
-	60532		USPAT;	2002/12/02 11	:04
	1	I	US-PGPUB; EPO; JPO;	I I	i
i	i	! !	DERWENT;	I	1
	1 10	 	IBM_TDB		
i -	!	(soi same transistor) same (silicon adj	USPAT; US~PGPUB;	2003/11/07 18	:20
	I	!	EPO; JPO;		i
i	1		DERWENT; IBM_TDB	1	1
-	15468	soi or (silicon near2 insulator)	USPAT;	2003/05/18 20	:25
l .			US-PGPUB	! !	
-	265	silicon near2 boat	USPAT; US-PGPUB	2003/05/18 20	:25
-	14	(soi or (silicon near2 insulator)) and	USPAT;	2003/05/18 20	:26
_	13	(silicon near2 boat) ((soi or (silicon near2 insulator)) and	US-PGPUB USPAT;	2003/05/18 20	. 22 !
	1	(silicon near2 boat)) and @ad<20020307	US-PGPUB	1 2003/03/18 20	.211
-	1	("6468884").PN.	USPAT;	2003/10/29 10	:53
_	4619	((438/149) or (438/311) or (438/459) or	US-PGPUB USPAT;	2003/11/07 14	18
	!	(438/584) or (438/706) or (438/758) or	US-PGPUB;		1
		(438/795) or (438/909) or (438/935)).CCLS.	EPO; JPO;	!	i
			DERWENT; IBM TDB	i	1
-	405	(silicon or ((single near2 crystal) adj	USPAT;	2003/11/07 14	:33
		silicon) or (poly near2 silicon) or (silicon near2 carbide)) near2 boat	US-PGPUB; EPO; JPO;	1	1
			DERWENT;		1
			IBM TDB		

	70	(([438/749] or (438/731) or (438/459) or (438/459) or (438/760) or (438/768) or (438/795) or (438/959) or (438/935)).CCLS.) and ((silicon or ((single near2 crystal) adj silicon) or (poly near2 silicon) or (silicon near2 carbido) near2 bost) near2 bost)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/07 14:26
i - !	100	(silicon near2 carbide) near2 boat	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/11/07 18:29
1	8	(((438/149) or (438/31)) or (438/59) or (438/58) or (438/58) or (438/706) or (438/795) or (438/909) or (438/935)).CCLS.) and ((silicon near2 carbide) near2 boat)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	1 2003/11/07 14:33
-		! 6296709.URPN. ! ("4640223" "4964378" "5001327" ! "5029554" "6139642"].PN.	USPAT	2003/11/07 14:37 2003/11/07 14:37